AC-Stark effect in a semi-spherical quantum dot

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We present a theoretical approach to study the effects of an ac-field applied to quantum dots with semi-spherical symmetry. Using the Floquet formalism for this periodically driven system, the timedependent Hamiltonian in the effective mass approximation is solved. We show that the Hilbert space of solutions is separated into orthogonal subspaces with different z-component of the angular momentum. We give an explicit analytical representation for electronic states as a function of the intensity and frequency of the electric field. Under the two level approximation, two particular cases are studied: the low- and high-frequency regimes, which result of comparing the ac-field frequency to the characteristic level splitting at zero field.

The dynamics of charged particles in semiconductor structures under a time-dependent external electric field has been a topic of intense research [1, 2, 3, 4, 5]. The progress of techniques on the nanoscale has made possible the systematic study of effects only present in intense alternating fields in this domain.

In this paper we address the problem of a quantum dot (QD) of semi-spherical shape with the ac-field along the axial symmetry of the dot (z-axis in this case) in a nonperturbative approach. To do so we make use of the Floquet formalism [1]. The Hamiltonian for an electron in the QD under an electric field of intensity F and frequency ω can be written as

$$H = H_o + |e| F z \sin(\omega t), \tag{1}$$

where $H_o = -(\hbar^2/2m^*)\nabla^2 + V_o$ is the Hamiltonian for the nondriven system. Here $V_o = 0$ inside the QD and we use hard-wall boundary conditions, m^* is the effective mass of the electron in the QD.

In the absence of the ac field the problem is exactly soluble and its eigenenergies are given by the square of the zeroes $\mu_n^{(l)}$ of the spherical Bessel functions, where n is the order of the zero and l the order of the Bessel function $J_{l+1/2}$ (see details in [6]). The eigenfunctions, in spherical coordinates, are given by

$$f_{n,l,m}^{(o)}(r,\theta,\phi) = \frac{1}{\sqrt{r}} \frac{J_{l+1/2}(\mu_n^{(l)} r)}{N_J} \frac{P_l^{|m|}(\cos\theta)}{N_P} \frac{e^{i m \phi}}{\sqrt{2\pi}},\tag{2}$$

where $P_l^{|m|}$ are the associated Legendre polynomials, m is the z-component of the angular momentum, and N_J and N_P are normalization constants.

The dynamics of the driven system is governed by the time-dependent Schroedinger equation

$$i\hbar\frac{\partial\Psi}{\partial t} = H\Psi.$$
(3)

Since *H* is periodic in time with period $\tau = 2\pi/\omega$, it is possible to use the standard Floquet theory [1] and write the wavefunction as $\Psi = \exp(-i\varepsilon t/\hbar)\Phi$, which allows us to rewrite Eq. (3) as

$$\left(H - i\hbar\frac{\partial}{\partial t}\right)\Phi(r,\theta,\phi,t) = \varepsilon \Phi(r,\theta,\phi,t),\tag{4}$$

where ε is a real-valued parameter termed the Floquet characteristic exponent, or the quasienergy.

To solve Eq. (4), Φ can be expanded in a Fourier series for the temporal component and linear combinations of stationary states

$$\Phi(r,\theta,\phi,t) = \sum_{p=-\infty}^{\infty} \exp(i\,p\,\omega\,t) \, u_p(r,\theta,\phi), \ p \in \mathcal{Z},$$
(5)

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FIG. 1: Some quasienergies with m = 0 as a function of the field for two zero-field energy levels. The indexes (α, p) are used to indicate the corresponding quasienergy at zero field. a) High-frequency regime with $\Omega = 40$, b) low-frequency regime with $\Omega = 20$.

where the index p labels the corresponding photon replicas [2]. The functions u_p are expanded in a series of solutions of H_o given by Eq. (2). Due to the axial symmetry, the Hilbert space of solutions is separated into orthogonal subspaces with different z-component of the angular momentum m. In what follows, we consider the subspace defined by m = 0, therefore, the number m is omitted. Then, the expansion of u_p is taken only over the pair of quantum numbers n, l which are labelled by the single index α :

$$u_p(r,\theta,\phi) = \sum_{\alpha=\{n,l\}}^{\infty} C_{\alpha}^{(\xi,\Omega)}(p) f_{\alpha}^{(o)}.$$
(6)

We introduced the dimensionless quantities $\xi = F/F_o$ and $\Omega = \hbar \omega/E_o$ where the units of energy and ac field intensity are $E_o = \hbar^2/2m^*a^2$ and $F_o = E_o/|e|a$, respectively, being a both the QD radius and the unit of distance. Substitution of Eqs. (5) and (6) in (4) leads to the time-independent eigenvalue problem, in terms of an infinite set of equations

$$\sum_{\{\alpha,p\}} \left[\left(\lambda - (\mu_{\alpha})^2 - p \,\Omega \right) \delta_{I,I'} - \frac{\xi}{2} \, \mathbf{Z}(\alpha, \alpha') \, \left(\delta_{p',p-1} + \delta_{p',p+1} \right) \right] C_I = 0, \tag{7}$$

where $Z(\alpha, \alpha') = \langle f_{\alpha}^{(0)} | r \cos \theta | f_{\alpha'}^{(0)} \rangle$ are the matrix elements coupling zero-field states. The quasienergy spectrum is determined by the interaction (coupling) among the nondriven levels and their replicas. Thus, when only one nondriven state is considered (i.e., one value of α in Eq. (7)), the interplay between the replicas is such that there is no variation of the levels at all as the electric field changes.

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In the framework of the two nondriven levels, which are the ground and the first excited states at m = 0, we obtain the quasienergy distributions shown in Fig. 1. According to the chosen units, $800F_0$ represents approximately 100 kV/cm for an InAs QD with a = 50 nm and for a CdSe QD with a = 30 nm. The field intensity would increase as the radius diminishes. In Fig. 1a) we present the high frequency regime ($\Omega > \Delta$, where $\Delta \approx 28.7$ is the dimensionless gap between these two levels) and in Fig. 1b) the low frequency regime ($\Omega < \Delta$). In both cases, suitable ranges of quasienergies were chosen for the analysis. At F = 0, the pair of numbers (α, p) are good quantum numbers, indicating the nondriven level and the corresponding replica. At $F \neq 0$, the field introduces mixing between states and (α, p) are not longer good quantum numbers to describe the spectrum, (see Eq. (7)). In Fig. 1a), the oscillating behaviour of quasienergy (1,0) is explained as follows: as the second term in Eq. (7) shows, this level only interacts with the nearby levels (2,-1) and (2,1), where it holds the condition $\Delta p = \pm 1$ with $\Delta p = p' - p$. We have not considered the interactions with their own replicas (1,-1) and (1,1) because they are negligible compared to the interactions with the closest level (2,-1). The proximity between levels (1,0) and (2,-1) makes them split off as the electric field is turned on, leading to the anticrossing in points A and A'. The separation between these levels can not increase unlimitedly because if it were greater than Ω it would produce a degeneracy between, for example, levels (1,0) and (2,0), which is not possible since they have the same spatial symmetry. On the other hand, the observed repulsion between levels (1,0) and (2,-1) and the periodicity of the system. As levels (1,0) and (2,-1) start to approach each other again, their direct interaction gives rise to the anticrossing C-C'. A similar explanation can be given for the replicas.

In the low-frequency regime shown in Fig. 1b), the anticrossings A-A', B-B'-B" and C-C' can be explained following the previous analysis. It can also be seen that the anticrossings occur at smaller values of the field, compared to Fig. 1a). To understand why, let us focus our attention on points A and A'. In this case, the level (1,0) is now closer to level (2,-1) than in Fig. 1a) and, in addition, interacts with level (2,1), which is not shown. While in Fig. 1a), these two levels are down and above level (1,0), respectively, here both of them are located above. Also notice that, in the high-frequency regime, the distribution of nearby levels with respect to level (1,0) produces repulsion over level (1,0) at opposite directions and in consequence a soft change as electric field increases, whereas in Fig. 1b) both levels repeal it in the same direction, causing a stronger effect. On the other hand, the more intense the electric field the higher the weight of the matrix elements $Z(\alpha, \alpha')$ in Eq. (7) and, in consequence, stronger admixture of the levels widens the gaps among them.

In conclusion, we have analyzed a semi-spherical quantum dot in the presence of an oscillating electric field. We have found, in agreement with recent analytical work in double and multiple quantum wells [2, 5], that the electric field at which the anticrossing occurs changes monotonically down as frequency decreases. An explanation was given in terms of the interaction among zero-field levels and their replicas. We have also studied the behaviour of the gaps between quasienergies at the anticrossing points and have found that the gaps increase with higher electric field due to the stronger admixture of the levels. When two zero-field levels are taken into account, there are two types of anticrossings. One of them (see points C and C' in each Figure) is due to a "direct" interaction between two nearby levels with $|\Delta p| = 1$. This type is characterized by a smooth variation of the quasienergy levels and occurs along a wide range of the field intensity. The second one (see points B and B" in each Figure) is due to an "indirect" interaction among the levels and the time periodicity of the system. It is characterized by an abrupt change which occurs in a very narrow interval of the field intensity. We also gave an explicit analytical representation for the functions defined by Eq. (3). These results can be very important and helpful for the interpretation of experimental data or theoretical calculations for driven tunneling structures in coupled multiple self-assembled quantum dots, and also to describe optical properties in the presence of an external ac field. Moreover, they can also be used to calculate the probability density and the time evolution of finding one particle in each quasienergy state.

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